One-dimensional electrical contact to a two-dimensional material

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#	Paper	IF	Citations
1980	WSe2 Light-Emitting Tunneling Transistors with Enhanced Brightness at Room Temperature.		
1979	Ballistic Transport in Graphene Antidot Lattices.		
1978	Transport Properties of a MoS2/WSe2 Heterojunction Transistor and Its Potential for Application.		
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1975	Imaging Bulk and Edge Transport near the Dirac Point in Graphene Moire Superlattices.		
1974	Transport Through a Network of Topological Channels in Twisted Bilayer Graphene.		
1973	All-Dry Transfer of Graphene Film by van der Waals Interactions.		
1972	Frictional Drag Effect between Massless and Massive Fermions in Single-Layer/Bilayer Graphene Heterostructures.		
1971	Tunable Room-Temperature Ferromagnetism in Two-Dimensional Cr2Te3.		1
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1967	Electron Tunneling through Boron Nitride Confirms MarcusHush Theory Predictions for Ultramicroelectrodes.		
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